SLLS213A - JANUARY 1996 - REVISED JUNE 1999

- Single Chip With Easy Interface Between **UART and Serial-Port Connector of an External Modem or Other Computer** Peripheral
- **Five Drivers and Three Receivers Meet or Exceed the Requirements of ANSI Standard** TIA/EIA-232-F and ITU Recommendation V.28 Standards
- Supports Data Rates up to 120 kbit/s
- Complement to the GD75232
- Provides Pin-to-Pin Replacement for the Goldstar GD75323
- **Pin-Out Compatible With SN75196**
- **Functional Replacement for the MC145405**

DW OR N PACKAGE (TOP VIEW) Vcc L 20 🛮 V_{DD} 1DA **∏** 2 19 1DY 2DA **∏** 3 18 2DY 3DA **∏** 4 17 **∏** 3DY 1RY **[**] 5 2RY [6 15 2RA 4DA **∏** 7 14**∏** 4DY 13 T 3RA 3RY [8 5DA **∏** 9 12 5DY GND **1** 10 11 [] V_{SS}

description

The GD75323 combines five drivers and three receivers from the trade-standard SN75188 and SN75189 bipolar quadruple drivers and receivers, respectively. The flow-through design of the GD75323 decreases the part count, reduces the board space required, and allows easy interconnection of the UART and serial-port connector. The all-bipolar circuits and processing of the GD75323 provide a rugged, low-cost solution for this function.

The GD75323 complies with the requirements of the ANSI TIA/EIA-232-F and ITU (formerly CCITT) V.28 standards. These standards are for data interchange between a host computer and a peripheral at signal rates up to 20 kbit/s. The switching speeds of the GD75323 are fast enough to support rates up to 120 kbit/s with lower capacitive loads (shorter cables). Interoperability at the higher signaling rates cannot be assured unless the designer has design control of the cable and the interface circuits at both ends. For interoperability at signaling rates up to 120 kbit/s, use of ANSI Standard TIA/EIA-423-B and TIA/EIA-422-B and ITU Recommendations V.10 and V.11 are recommended.

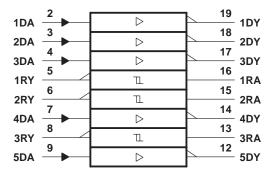
The GD75323 is characterized for operation over a temperature range of 0°C to 70°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



logic symbol†

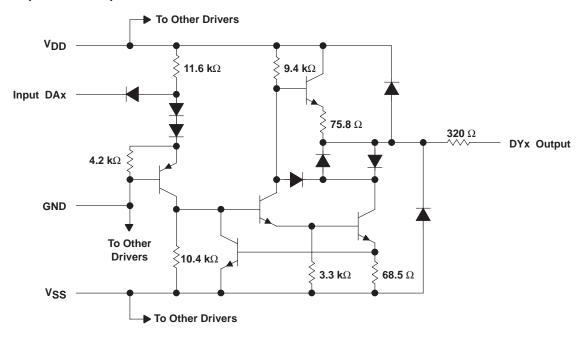


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)

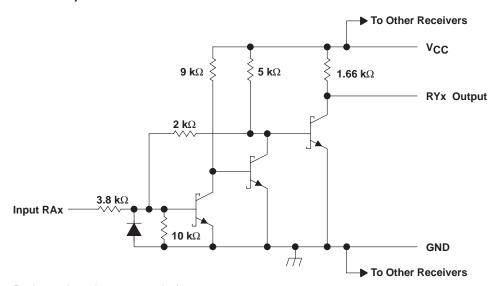


schematic (each driver)



Resistor values shown are nominal.

schematic (each receiver)



Resistor values shown are nominal.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)	10 V
Supply voltage, V _{DD} (see Note 1)	15 V
Supply voltage, V _{SS} (see Note 1)	
Input voltage range, V _I : Driver	–15 V to 7 V
Receiver	30 V to 30 V
Output voltage range, VO (Driver)	– 15 V to 15 V
Low-level output current, IOL (Receiver)	20 mA
Package thermal impedance, θ _{JA} (see Note 2): [DW package 97°C/W
1	N package 67°C/W
Lead temperature 1,6 mm (1/16 inch) from case for	or 10 seconds
Storage temperature range, T _{stg}	– 65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		MIN	NOM	MAX	UNIT
	V_{DD}	7.5	9	13.5	
Supply voltage	V _{SS}	-7.5	-9	-13.5	V
	Vcc	4.5	5	5.5	
High-level input voltage, VIH	Driver	1.9			V
Low-level input voltage, V _{IL}	Driver			0.8	V
High lovel output ourrent love	Driver			-6	mA
nigh-level output current, IOH	Receiver			-0.5	ША
High lovel output ourrent les	Driver			6	mA
w-level input voltage, V _{IL} gh-level output current, I _{OL}	Receiver			16	IIIA
Operating free-air temperature,TA		0		70	°C

supply currents over operating free-air temperature range

	PARAMETER		TEST CONDIT	TIONS		MIN	MAX	UNIT	
		All inputs at 1.9 V,	No load	$V_{DD} = 9 V$,	$V_{SS} = -9 V$		25	mA	
,	Supply current from VDD	All inputs at 1.9 v,	NO IOAU	V _{DD} = 12 V,	$V_{SS} = -12 \text{ V}$		32	IIIA	
IDD	Supply current from VDD	All inputs at 0.8 V,	No load	V _{DD} = 9 V,	$V_{SS} = -9 V$		7.5	mA	
		All illputs at 0.0 v,	No load	V _{DD} = 12 V,	$V_{SS} = -12 \text{ V}$		9.5	IIIA	
		All inputs at 1.9 V,	No load	$V_{DD} = 9 V$,	$V_{SS} = -9 V$		-25	mA	
las	Cupply ourront from Vaa	All inputs at 1.9 v,	NO IOAU	V _{DD} = 12 V,	$V_{SS} = -12 \text{ V}$		-32	IIIA	
ISS	Supply current from VSS	All inputs at 0.8 V,	No load	$V_{DD} = 9 V$,	V _{SS} = -9 V		-5.3	m A	
		All inputs at 0.6 v,	No load	V _{DD} = 12 V,	$V_{SS} = -12 \text{ V}$		-5.3	mA	
ICC	Supply current from V _{CC}	V _{CC} = 5 V,	All inputs at 5 V,	No load			20	mA	



NOTES: 1. All voltages are with respect to the network ground terminal.

^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

DRIVER SECTION

electrical characteristics over operating free-air temperature range, V_{DD} = 9 V, V_{SS} = -9 V, V_{CC} = 5 V (unless otherwise noted)

	PARAMETER		TEST CONDITIO	MIN	TYP	MAX	UNIT	
Vон	High-level output voltage	V _{IL} = 0.8 V,	$R_L = 3 k\Omega$,	See Figure 1	6	7.5		V
V _{OL}	Low-level output voltage (see Note 3)	V _{IH} = 1.9 V,	$R_L = 3 k\Omega$,	See Figure 1		-7.5	-6	V
lн	High-level input current	V _I = 5 V,	See Figure 2				10	μΑ
Ι _Ι L	Low-level input current	$V_{I} = 0,$	See Figure 2				-1.6	mA
IOS(H)	High-level short-circuit output current (see Note 4)	V _{IL} = 0.8 V,	V _O = 0,	See Figure 1	-4.5	-9	-19.5	mA
IOS(L)	Low-level short-circuit output current	V _{IH} = 2 V,	$V_{O} = 0$,	See Figure 1	4.5	9	19	mA
ro	Output resistance (see Note 5)	VCC = VDD =	$V_{SS} = 0$,	$V_0 = -2 \text{ V to } 2 \text{ V}$	300			Ω

- NOTES: 3. The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only, e.g., if –10 V is maximum, the typical value is a more negative voltage.
 - 4. Output short-circuit conditions must maintain the total power dissipation below absolute maximum ratings.
 - 5. Test conditions are those specified by TIA/EIA-232-F and as listed above.

switching characteristics, V_{DD} = 12 V, V_{SS} = -12 V, V_{CC} = 5 V $\pm 10\%$, T_A = 25°C

	PARAMETER	TEST CONDITI	ONS	MIN	TYP	MAX	UNIT
^t PLH	Propagation delay time, low- to high-level output	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	C _L = 15 pF,		315	500	ns
tPHL	Propagation delay time, high- to low-level output	See Figure 3			75	175	ns
	Transition time law to high level output	R_L = 3 kΩ to 7 kΩ, See Figure 3	C _L = 15 pF,		60	100	ns
^t TLH	Transition time, low- to high-level output	R_L = 3 kΩ to 7 kΩ, See Figure 3 and Note 6	$C_L = 2500 \text{ pF},$		1.7	2.5	μs
Transition time, high- to low-level output (see		R_L = 3 kΩ to 7 kΩ, See Figure 3	C _L = 15 pF,		40	75	ns
[†] THL	Note 5)	R_L = 3 kΩ to 7 kΩ, See Figure 3 and Note 7	$C_L = 2500 \text{ pF},$		1.5	2.5	μs

- NOTES: 6. Measured between 3-V and 3-V points of the output waveform (TIA/EIA-232-F conditions), all unused inputs are tied either high or low.
 - 7. Measured between 3-V and -3-V points of the output waveform (TIA/EIA-232-F conditions), all unused inputs are tied either high or low.



RECEIVER SECTION

electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST C	ONDITIONS	MIN	TYP [†]	MAX	UNIT
\/	V _{IT+} Positive-going input threshold voltage		T _A = 25°C	1.75	1.9	2.3	
VIT+	Fositive-going input tilleshold voltage	See Figure 5	$T_A = 0$ °C to 70 °C	1.55		2.3	V
V _{IT} –	Negative-going input threshold voltage	See Figure 5		0.75	0.97	1.25	V
V _{hys}	Input hysteresis voltage (V _{IT+} - V _{IT-})	See Figure 5		0.5			
Vou	VOH High-level output voltage		V _{IH} = 0.75 V	2.6	4	5	V
VOH	riigii-ievei output voitage	$I_{OH} = -0.5 \text{ mA}$	Inputs open	2.6			٧
VOL	Low-level output voltage	$I_{OL} = 10 \text{ mA},$	V _I = 3 V		0.2	0.45	V
	High-level input current	V _I = 25 V,	See Figure 5	3.6		8.3	mA
ΊΗ	riigir-ieveriiiput current	V _I = 3 V,	See Figure 5	0.43			IIIA
1	III Low-level input current		See Figure 5	-3.6		-8.3	mA
¹IL	Low-level input current	$V_{I} = -3 V$,	See Figure 5	-0.43			IIIA
los	Short-circuit output current	See Figure 4	·		-3.4	-12	mA

[†] All typical values are at $T_A = 25^{\circ}C$, $V_{CC} = 5$ V, $V_{DD} = 9$ V, and $V_{SS} = -9$ V.

switching characteristics, V_{CC} = 5 V, V_{DD} = 12 V, V_{SS} = -12 V, T_A = 25°C

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low- to high-level output				107	500	ns
tPHL	Propagation delay time, high- to low-level output	$C_L = 50 \text{ pF},$	$R_L = 5 k\Omega$,		42	150	ns
^t TLH	Transition time, low- to high-level output	See Figure 6			175	525	ns
tTHL	Transition time, high- to low-level output				16	60	ns

PARAMETER MEASUREMENT INFORMATION

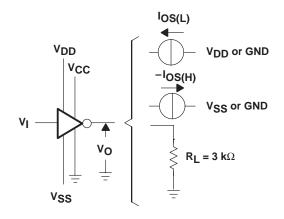


Figure 1. Driver Test Circuit for V_{OH} , V_{OL} , $I_{OS(H)}$, and $I_{OS(L)}$

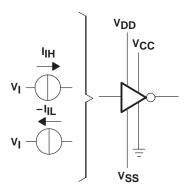
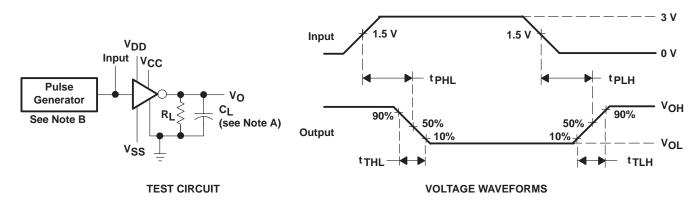


Figure 2. Driver Test Circuit for $I_{\mbox{\scriptsize IH}}$ and $I_{\mbox{\scriptsize IL}}$



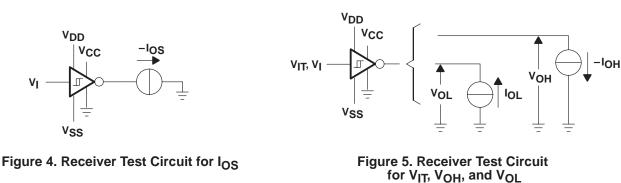
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

B. The pulse generator has the following characteristics: t_W = 25 μ s, PRR = 20 kHz, Z_O = 50 Ω , t_r = t_f < 50 ns.

Figure 3. Driver Test Circuit and Voltage Waveforms



50% 50% Input -5 V ^tPHL ^tPLH Vон 90% 50% 50% Output 10% 10% Vol tTHLtTLH

VOLTAGE WAVEFORMS

Input **Pulse** ۷o Generator See Note B (see Note A) VSS

NOTES: A. C_I includes probe and jig capacitance.

TEST CIRCUIT

 V_{DD}

B. The pulse generator has the following characteristics: $t_W = 25 \,\mu s$, PRR = 20 kHz, $Z_O = 50 \,\Omega$, $t_T = t_f < 50 \,ns$.

Figure 6. Receiver Propagation and Transition Times

TYPICAL CHARACTERISTICS DRIVER SECTION

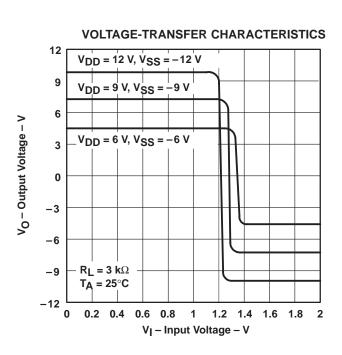
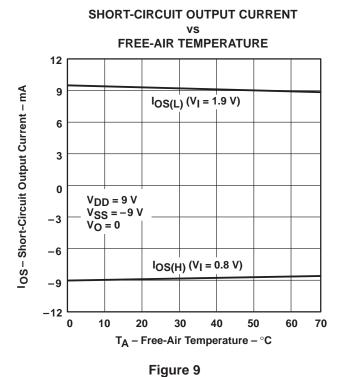
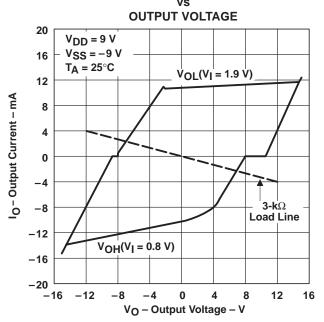


Figure 7





OUTPUT CURRENT

Figure 8

SLEW RATE vs LOAD CAPACITANCE

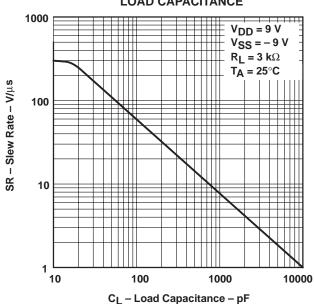


Figure 10



TYPICAL CHARACTERISTICS **RECEIVER SECTION**

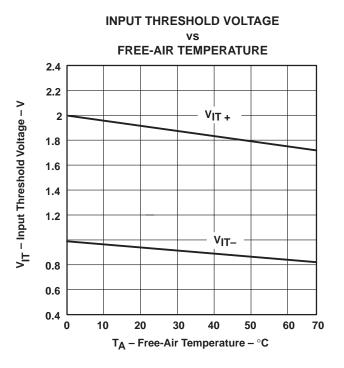
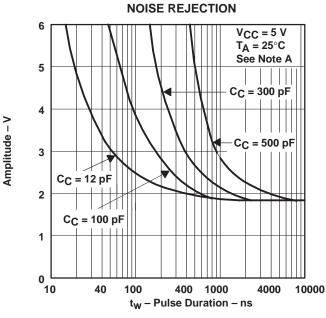


Figure 11



NOTE A: This figure shows the maximum amplitude of a positive-going pulse that, starting from 0 V, does not cause a change of the output level.

Figure 13

INPUT THRESHOLD VOLTAGE SUPPLY VOLTAGE 2 $V_{\text{IT+}}$ 1.8 V_{IT} - Input Threshold Voltage - V 1.6 1.4 1.2 1 V_{IT}-0.8 0.6 0.4 0.2 0 2 3 5 8 9 10 V_{CC} - Supply Voltage - V

Figure 12

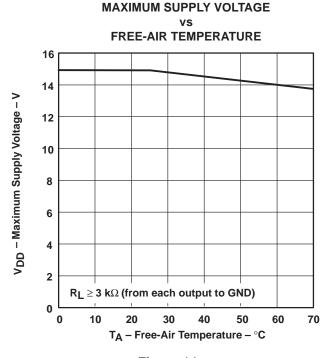


Figure 14



APPLICATION INFORMATION

Diodes placed in series with the V_{DD} and V_{SS} leads protect the GD75323 in the fault condition in which the device outputs are shorted to V_{DD} or V_{SS} , and the power supplies are at low and provide low-impedance paths to ground (see Figure 15).

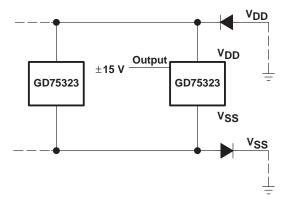
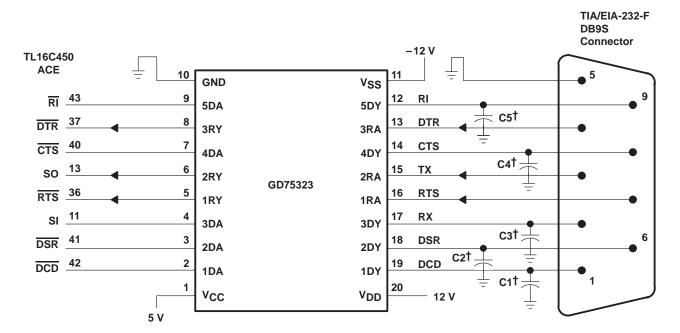


Figure 15. Power-Supply Protection to Meet Power-Off Fault Conditions of TIA/EIA-232-F



[†] See Figure 10 to select the correct values for the loading capacitors (C1, C2, C3, C4, and C5), which may be required to meet the RS-232 maximum slew-rate requirement of 30 V/μs. The value of the loading capacitors required depends upon the line length and desired slew rate, but is typically 330 pF.

NOTE C: To use the receivers only, VDD and VSS both must be powered or tied to ground.

Figure 16. Typical Connection



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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
GD75323DW	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75323
GD75323DW.A	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75323
GD75323DWR	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75323
GD75323DWR.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75323

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

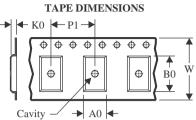
⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
GD75323DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
GD75323DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Type Package Drawing		SPQ	Length (mm)	Width (mm)	Height (mm)	
GD75323DWR	SOIC	DW	20	2000	350.0	350.0	43.0	
GD75323DWR	SOIC	DW	20	2000	367.0	367.0	45.0	

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
GD75323DW	DW	SOIC	20	25	507	12.83	5080	6.6
GD75323DW	DW	SOIC	20	25	506.98	12.7	4826	6.6
GD75323DW.A	DW	SOIC	20	25	506.98	12.7	4826	6.6
GD75323DW.A	DW	SOIC	20	25	507	12.83	5080	6.6



SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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